

80 µA (Typ) 5.0 V (Typ)

500 mA

±2 %

LDO Regulators with Watch-Dog Timer

500mA Output LDO Regulators with Voltage Detector and Watchdog Timer

BD3020HFP BD3021HFP

General Description

BD3020HFP BD3021HFP is a regulator IC with integrated WDT (Watch Dog Timer), high output voltage accuracy ±2.0 % and 80 µA (Typ) low circuit current consumption. These are supports usage of low ESR ceramic capacitor for output stability. The reset detection voltage can be adjusted by connecting resistors on the Vs terminal (BD3020HFP). They can be a stable power supply for any applications while detecting malfunction of microcontrollers.

Features

- Integrated WDT Reset Circuit [BD3020HFP]: Adjustable Detection Voltage through Vs pin [BD3021HFP]: WDT Can be Switched ON / OFF by Using INH Pin
- Low saturation voltage by using PMOS output transistor
- VCC Max Voltage: 50 V
- Integrated Over Current Protection and Thermal Shut Down
- HRP7 package

Key specification

- Low Circuit Current:
- Output Voltage:
- Output Current:
- High Output Voltage Accuracy:
- Low ESR ceramic capacitor can be used as output capacitor

Package

 $W(Typ) \times D(Typ) \times H(Max)$ HRP7 9.395 mm × 10.540 mm × 2.005 mm



Figure 1. Package Outlook

Applications

Automotive (body, audio system, navigation system, etc.)

Typical Application Circuits

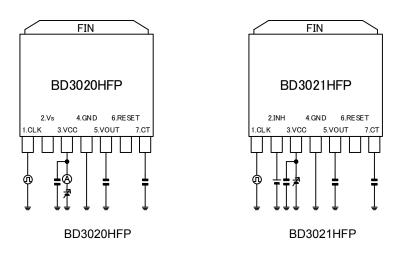
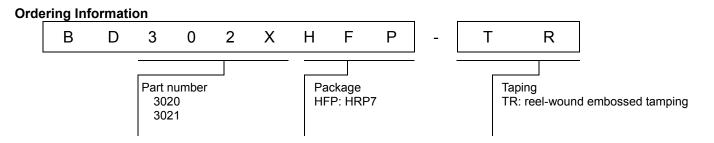


Figure 2. Typical Application Circuits

OProduct structure : Silicon monolithic integrated circuit OThis product is not designed protection against radioactive rays



Pin Configuration

Pin Description

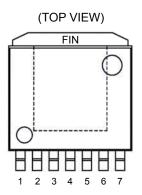
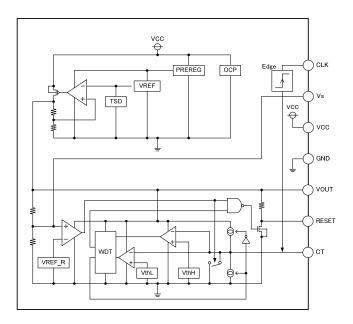


Figure 3. Pin Configuration

Pin No.	Pin Name	Function
1	CLK	Clock Input from Microcontroller
2	Vs (BD3020HFP)	Reset Detection Voltage Set Pin
2	INH (BD3021HFP)	WDT ON/OFF Function Pin
3	VCC	Power Supply Pin
4	GND	GND
5	VOUT	Voltage Output Pin
6	RESET	Reset Output Pin
7	СТ	External Capacitance for Reset Output Delay Time, WDT Monitor Time Setting Connection Pin
Fin	GND	GND

Block Diagram

<BD3020HFP>



<BD3021HFP>

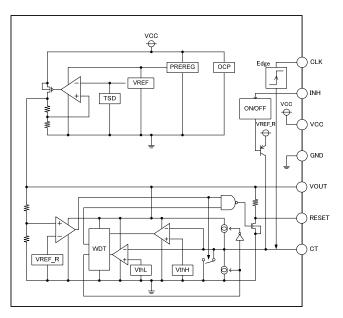


Figure 4. Block Diagrams

Absolute Maximum Ratings (Ta = 25 °C)

Parameter	Symbol	Ratings	Unit
Supply Voltage (1)	Vcc	-0.3 to +50.0	V
Vs pin Voltage (BD3020HFP)	Vs	-0.3 to +15.0	V
INH pin Voltage (BD3021HFP)	VINH	-0.3 to +15.0	V
Regulator Output pin Voltage	Vout	-0.3 to +15.0	V
Reset Output pin Voltage	Vreset	-0.3 to +15.0	V
Watchdog Input pin Voltage	Vclk	-0.3 to +15.0	V
Reset Delay Setting pin Voltage	Vct	-0.3 to +15.0	V
Power Dissipation (2)	Pd	1.6	W
Operating Temperature Range	Topr	-40 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	150	°C

(1) Pd should not be exceeded.

(2) HRP7 mounted on 70.0 mm × 70.0 mm × 1.6 mmt Glass-Epoxy PCB. If Ta ≥ 25 °C, reduce by 12.8 mW / °C.

(1-layer PCB: Copper foil area on the reverse side of PCB: 0 mm × 0 mm) Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Operating Conditions (-40°C \leq Ta \leq +125 °C)

Parameter	Symbol	Min	Max	Unit
Supply Voltage (3)	V _{CC}	5.6	36.0	V
Output Current	lo	0	500	mA

(3) For the output voltage, consider the voltage drop (dropout voltage) due to the output current.

BD3020HFP BD3021HFP

Electrical Characteristics (Unless otherwise specified, -40°C ≤ Ta ≤ +125 °C, V_{CC} = 13.5 V, V_{CLK} = GND)

Parameter	Symbol	Limit		11:+	Conditions		
Parameter	Symbol	Min	Тур	Max	Unit	Conditions	
Overall Device							
Bias Current 1	lcc1	_	80	130	μA	lo = 0 mA	
Bias Current 2	lcc2	-	150	300	μA	lo = 50 mA (Ta = 25 °C)	
Regulator							
Output Voltage	V _{OUT}	4.90	5.00	5.10	V	lo = 200 mA	
Line Regulation	Line.Reg	_	5	35	mV	5.6 V ≤ V _{CC} ≤ 36 V	
Load Regulation	Load.Reg	-	30	70	mV	5 mA ≤ lo ≤ 200 mA	
Dropout Voltage	ΔVd	_	0.3	0.6	V	V _{CC} = 4.75 V, Io = 200 mA	
Ripple Rejection	R.R.	45	55	_	dB	f = 120Hz, ein = 1 Vrms, lo = 100 mA	
Reset							
Detection Voltage (BD3020HFP)	Vdet	4.02	4.10	4.18	V		
Detection Voltage (BD3021HFP)	Vdet	4.40	4.50	4.60	V		
Hysteresis Width	V _{HS}	50	100	150	mV		
Output Delay Time Low→High (Power On Reset Time)	talh	1.1	1.9	2.7	ms	V_{CC} = Vdet ±0.5 V (V_{CC} = V_{OUT}) INH = open ⁽¹⁾ , C_{CT} = 0.01 µF	
Output Delay Time High→Low	tань	-	100	300	μs	V_{CC} = Vdet ±0.5 V (V_{CC} = V_{OUT}) INH = open ⁽¹⁾ , C_{CT} = 0.01 µF	
RESET Discharge Current	IRESET	0.2	_	_	mA	V _{CC} = 1.5 V, V _{RESET} = 0.5 V (V _{CC} = V _{OUT})	
CT Discharge Current	lct	0.1	_	_	mA	V _{CC} = 1.5 V, V _{CT} = 0.5 V (V _{CC} = V _{OUT})	
Low Output Voltage	Vrst	I	0.1	0.2	V	V _{OUT} = 4.0 V	
Min Operating Voltage	Vopl	1.5	-	_	V		

(1) BD3021HFP only

BD3020HFP BD3021HFP

Electrical Characteristics (Unless otherwise specified, -40°C, ≤ Ta ≤ +125 °C, V_{CC} = 13.5 V, V_{CLK} = GND)

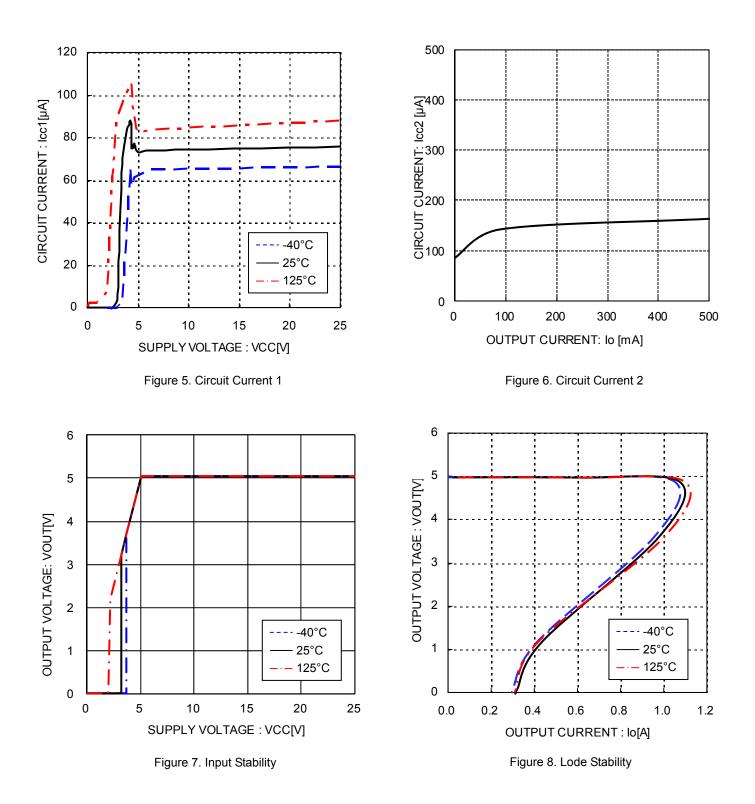
						C, VCC = 13.5 V, VCLK = GIND)		
Parameter	Symbol	Limit		Unit	Conditions			
Falanelei	Symbol	Min	Тур	Max	Unit	Conditions		
Watchdog timer								
CT Switching Threshold Voltage High	VthH	1.08	1.15	1.25	V	WDT ON ⁽¹⁾ , INH = open ⁽¹⁾		
CT Switching Threshold Voltage Low	VthL	0.13	0.15	0.17	V	WDT $ON^{(1)}$, INH = $open^{(1)}$		
WDT Charge Current	lctc	3.5	6.0	8.5	μA	WDT ON ⁽¹⁾ , INH = open ⁽¹⁾ V _{CT} = 0 V		
WDT Discharge Current	lctd	1.2	2.0	2.8	μA	WDT ON ⁽¹⁾ , INH = open ⁽¹⁾ V _{CT} = 1.3 V		
Watchdog Monitor Time Low	twн	3.0	5.0	7.0	ms	WDT ON ⁽¹⁾ , INH = open ⁽¹⁾ , C _{CT} = 0.01 μ F (Ceramic Capacitor) ⁽²⁾		
Watchdog Reset Time	t _{WL}	1.0	1.7	2.4	ms			
CLK Input Pulse Width	twclk	500	-	-	ns			
INH*								
WDT OFF Threshold Voltage	V _{HINH}	V _{оит} × 0.8	-	Vout	V			
WDT ON Threshold Voltage	VLINH	0	-	V _{ОUT} × 0.3	v	INH is pulled down inside the IC when INH open.		
INH Input current	Iinh	-	10	20	μA	V _{INH} = 5 V		

(1) BD3021HFP only

(2) Characteristics of ceramic capacitor not considered.

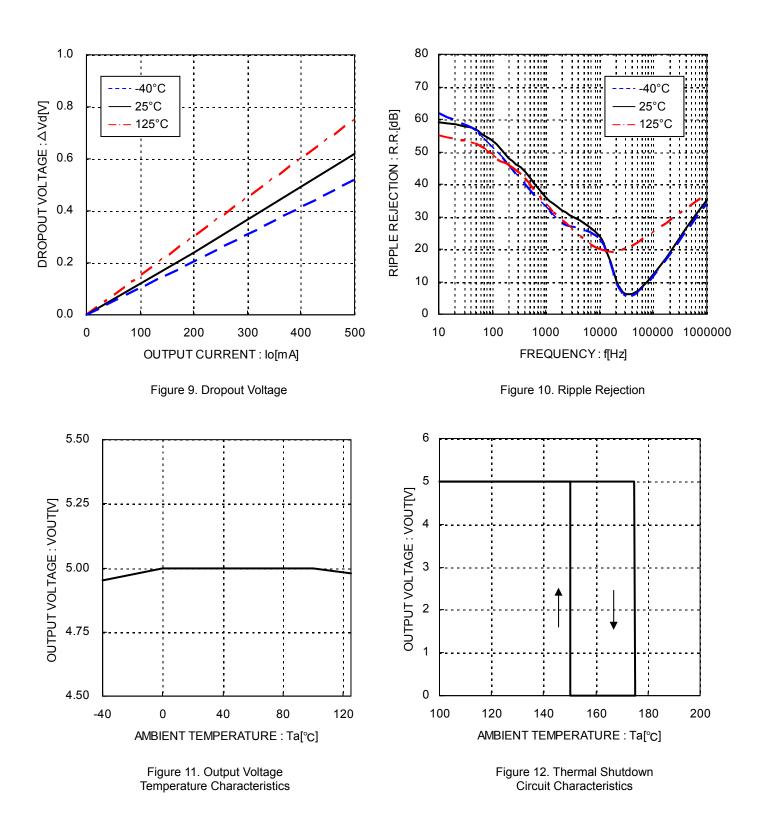
Reference data

Unless otherwise specified, Ta = 25 °C, V_{CC} = 13.5 V, V_{CLK} = GND



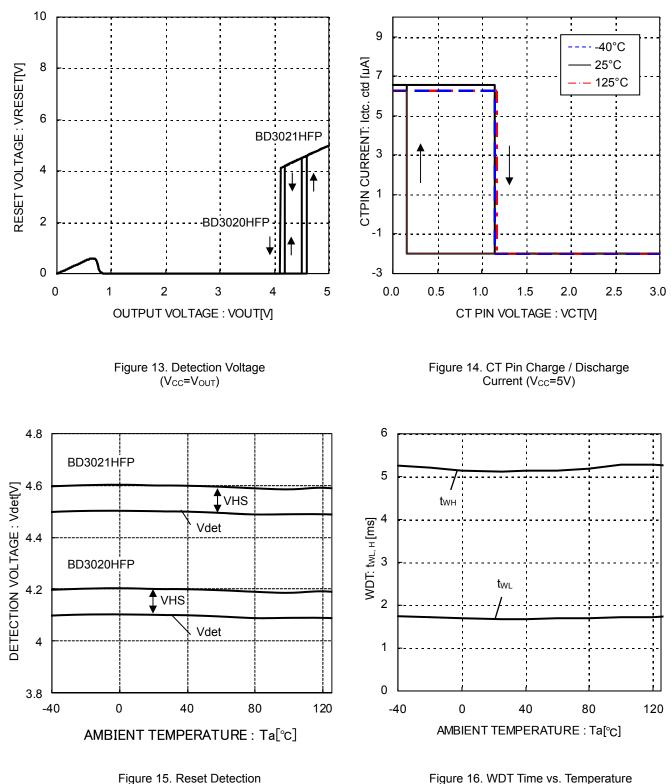
Reference data

Unless otherwise specified, Ta = 25 °C, V_{CC} = 13.5 V, V_{CLK} = GND



Reference data

Unless otherwise specified, Ta = 25 °C, V_{CC} = 13.5 V, V_{CLK} = GND



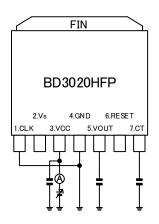
(C_{CT}=0.01µF)

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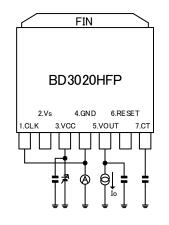
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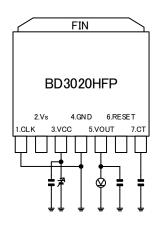
Measurement Circuits (BD3020HFP)



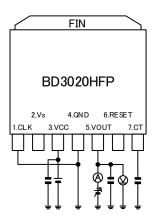
Measurement setup for Figure 5.



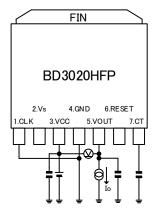
Measurement setup for Figure 6.



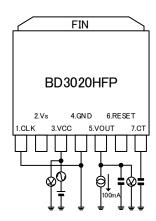
Measurement setup for Figure 7, 11, 12.



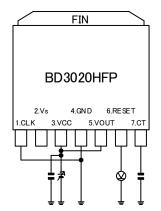
Measurement setup for Figure 8.



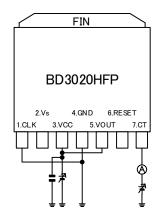
Measurement setup for Figure 9.



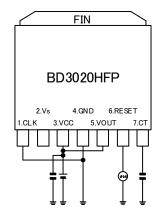
Measurement setup for Figure 10.



Measurement setup for Figure 13, 15.

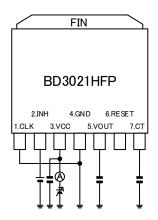


Measurement setup for Figure 14.

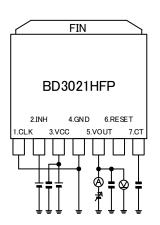


Measurement setup for Figure 16.

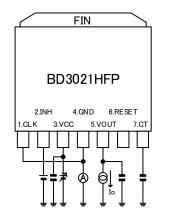
Measurement Circuits (BD3021HFP)



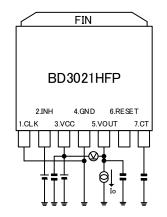
Measurement setup for Figure 5.



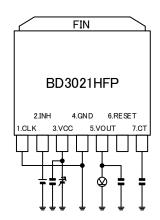
Measurement setup for Figure 8.



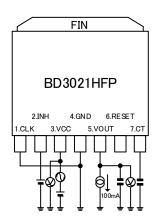
Measurement setup for Figure 6.



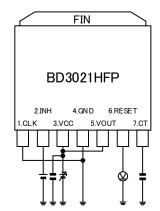
Measurement setup for Figure 9.



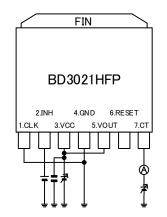
Measurement setup for Figure 7, 11, 12.



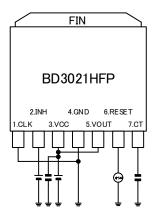
Measurement setup for Figure 10.



Measurement setup for Figure 13, 15.



Measurement setup for Figure 14.



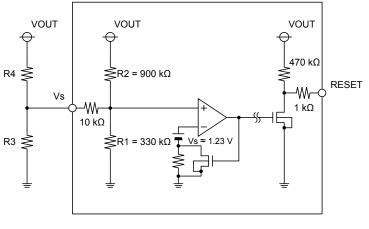
Measurement setup for Figure 16.

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BD3020HFP Detection Voltage Adjustment (Resistance value is typical value)



IC Internal Block Diagram

When typical detection voltage is 4.1 V

- Vdet ≈ Vs × (R1 + R2) / R1
- Vdet : Reset detection voltage
- Vs : Internal reference voltage (MOS input)
- R1, R2 : IC internal resistor
 - (Voltage detection precision is tightened up to ±2 % by laser-trimming the R1 and R2)

Vs will fluctuate 1.23 V ±6.0 %.

The reset detection voltage can be adjusted by connecting resistors on the Vs terminal.

Insert pull down resistor R3 (lower resistance than R1) in between Vs-GND, and pull down resistor R4 (lower resistance than R2) in between Vs-VOUT to adjust the detection voltage.

By doing so, the detection voltage can be adjusted by the calculation below.

Vdet = Vs × [{R2 × R4 / (R2 + R4)} + {R1 × R3 / (R1 + R3)}] / {R1 × R3 / (R1+R3)}

When the output resistance value is as small enough to ignore the IC internal resistance, you can find the detection voltage by the calculation below.

Vdet ≈ Vs × (R3 + R4) / R3

Adjust the resistance value by application as the circuit current will increase due to the added resistor.

BD3020/21HFP Power on Reset / Watchdog Timer

Power ON reset (output delay time) is adjustable by CT pin capacitor.

t _{dLH} (S) ≈ (1.15 V :	CT capacitance	(μF)) / Ictc (μA) (Typ)
----------------------------------	----------------	-------------------------

- tdLH : Output delay time (power ON reset)
- 1.15 V : Upper switching threshold voltage (Typ)
- CT capacitance : Capacitor connected to CT pin
- Ictc : WDT charge current

Calculation example) with 0.01 μF CT pin capacitor

t_{dLH} (S) = 1.15 V × 0.01 μF / 6 μA

≈ 1.9 ms

*If the CT capacitance is not the same as the condition on the electrical characteristics table, i.e., 0.01 µF, choose the capacitance value in ratio referring to the above equation.

Watch Dog Timer (WDT $t_{\text{WH}},\,t_{\text{WL}})$ is adjustable by the CT pin capacitor

 $t_{W H}$ (S) \approx 1.00 V × CT capacitance (µF)) / Ictd(µA) (Typ)

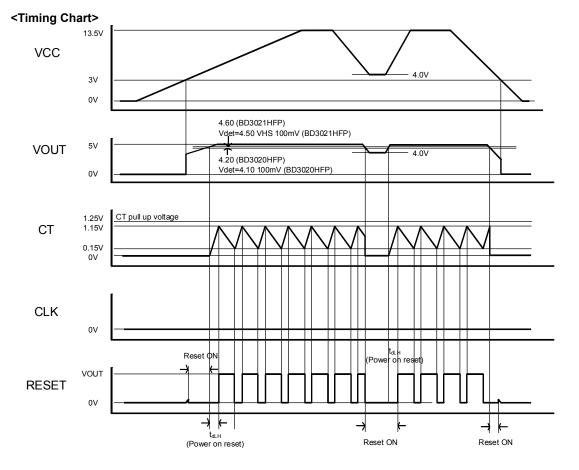
- $t_{W L}$ (S) \approx 1.00 V × CT capacitance (µF)) / Ictc(µA) (Typ)
- t_{WH} : Watchdog monitor time Low (delay time to turn the reset ON)
- t_{WL} : Watchdog reset time (time the reset is ON)
- 1.00 V : Upper switching threshold voltage lower switching threshold voltage
- CT capacitance : CT pin capacitor *Shared with power ON reset
- Ictc : WDT charge current
- Ictd : WDT discharge current

Calculation example) with 0.01 μF CT pin capacitor

 $t_{W H}$ (S) \approx 1.00 V \times 0.01 μ F / 2 μ A \approx 5.0 ms (Typ)

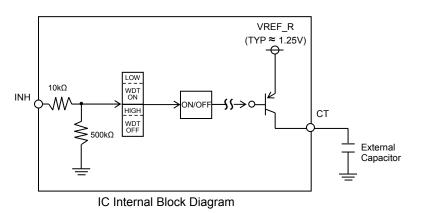
t_{W L} (S) ≈ 1.00 V × 0.01 μ F / 6 μ A ≈ 1.7 ms (Typ)

*If the CT capacitance is not the same as the condition on the electrical characteristics table, i.e., 0.01 µF, choose the capacitance value in ratio referring to the above equation.



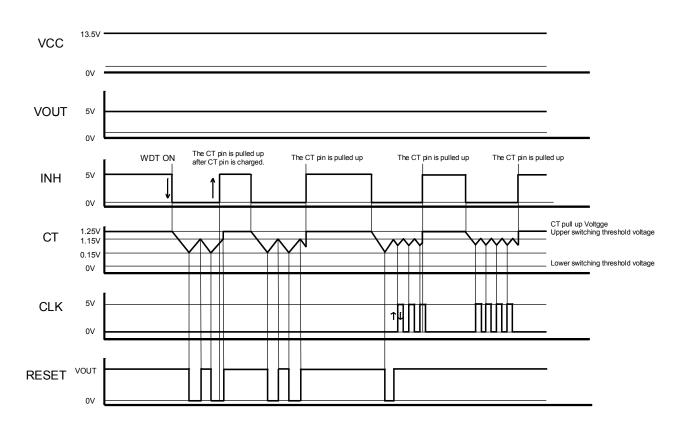
WDT timer ON / OFF switch INH (Resistance value is typical value)

BD3021HFP has a switch INH to turn the WDT ON / OFF.

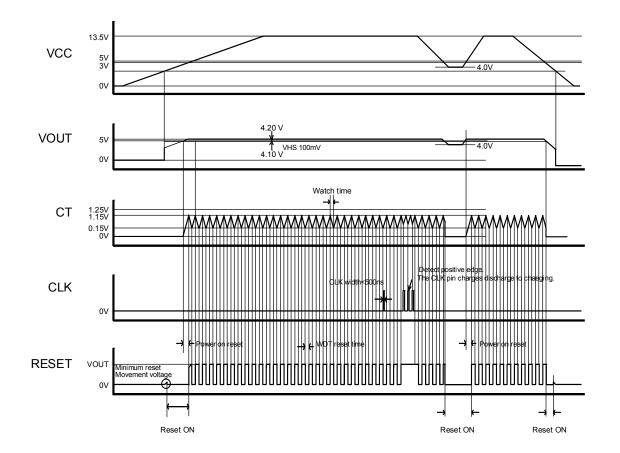


By using INH ON, CT potential can be pulled up to internal voltage VREF_R (invalid with power ON reset).

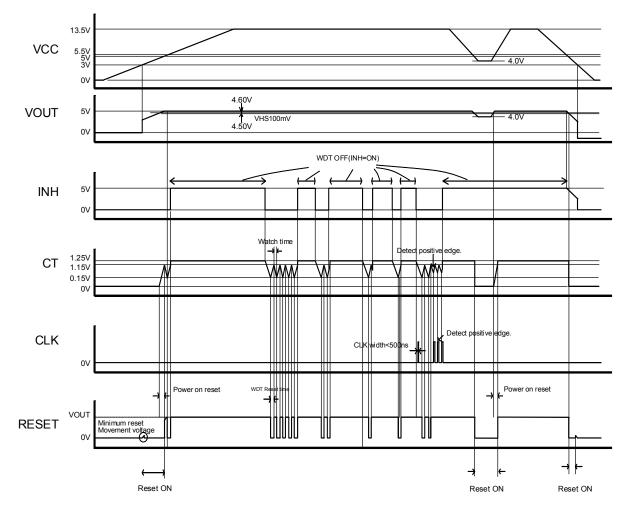
<Timing Chart> BD3021HFP



<Timing Chart> BD3020HFP



<Timing Chart> BD3021HFP



Pin Settings / Precautions

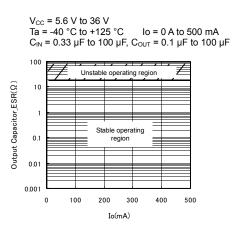
1. VCC Pin

Insert a 0.33 μ F to 1000 μ F capacitor between the VCC and GND. The appropriate capacitance value varies by application. Be sure to allow a sufficient margin for input voltage levels.

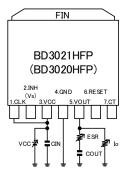
2. Output pins

In order to prevent oscillation, a capacitor needs to be placed between the output pin and GND. We recommend using a capacitor with a capacitance of 0.1 μ F to 1000 μ F. Electrolytic, tantalum and ceramic capacitors can be used. When selecting the capacitor ensure that the capacitance of 0.1 μ F to 1000 μ F is maintained at the intended applied voltage and temperature range. Due to changes in temperature the capacitor's capacitance can fluctuate possibly resulting in oscillation. For selection of the capacitor refer to the Cout_ESR vs. Io data. The stable operation range given in the reference data is based on the standalone IC and resistive load. For actual applications the stable operating range is influenced by the PCB impedance, input supply impedance and load impedance. Therefore verification of the final operating environment is needed.

Also, in case of rapidly changing input voltage and load current, select the capacitance in accordance with verifying that the actual application meets with the required specification.



Output Capacitor ESR vs lo (reference data)



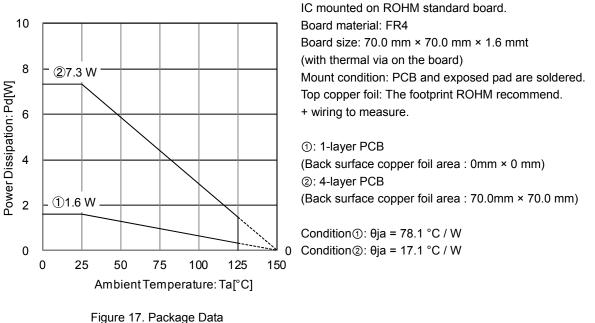
*Pin Settings / Precautions2 Measurement circuit

3. CT pin

Connecting a capacitance of 0.01 μF to 1 μF on the CT pin is recommended.

Power Dissipation

■HRP7



(HRP7)

Refer to Figure 17 thermal dissipation characteristics for usage above Ta = 25 °C. The IC's characteristics are affected heavily by the temperature, and if is exceeds its max junction temperature (Tjmax), the chip may degrade or destruct. Thermal design is critical in terms of avoiding Instantaneous destruction and reliability in long term usage. The IC needs to be operated below its max junction temperature (Tjmax) to avoid thermal destruction. Refer to Figure 17 for HRP7 package thermal dissipation characteristics. Operate the IC within power dissipation (Pd) when using this IC.

Vcc

: Input Voltage

Power consumption Pc (W) calculation will be as below

	Vout :	Output Voltage
$Pc = (V_{CC} - V_{OUT}) \times Io + V_{CC} \times Icc$	lo	: Load Current
Power dissipation $Pd \ge Pc$	lcc	: Circuit Current

If load current lo is calculated to operate within power dissipation, it will be as below, where you can find the max load current IoMax for the applied voltage V_{CC} of the thermal design.

$$lo \le \frac{Pd - V_{CC} \times lcc}{V_{CC} - V_{OUT}}$$
 (Refer to Figure 6 for the lcc)

■Example) at Ta = 125 °C, V_{CC} = 12 V, V_{OUT} = 5 V

$$lo \leq \frac{1.452 - 12 \times lcc}{12 - 5}$$

$$lo \leq 207 \text{ mA (lcc: 150 } \mu\text{A})$$

$$\theta ja = 17.1 ^{\circ}\text{C / W} \rightarrow -58.4 \text{ mV / }^{\circ}\text{C}$$

$$25 ^{\circ}\text{C} = 7.30 \text{ W} \rightarrow 125 ^{\circ}\text{C} = 1.452 \text{ W}$$

At Ta = 125 °C with Figure 17 ② condition, the calculation shows that ca 207 mA of output current is possible at 7 V potential difference across input and output.

I/O Equivalence Circuit (Resistance value is typical value)

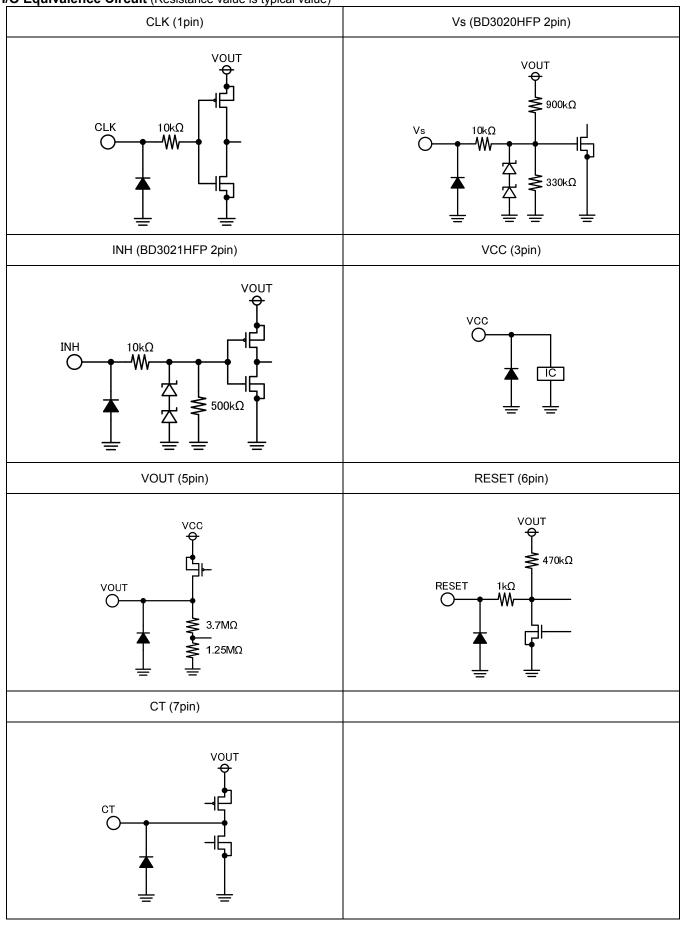


Figure 18. I / O equivalence circuit

Operational Notes

1. Electrical characteristics

Electrical characteristics described in these specifications may vary, depending on temperature, supply voltage, external circuits and other conditions. Therefore, be sure to check all relevant factors, including transient characteristics.

2. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

3. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

4. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

5. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

6. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

Use a thermal design that allows for a sufficient margin in light of the Pd in actual operating conditions. Consider Pc that does not exceed Pd in actual operating conditions. (Pd \ge Pc)

Tjmax: Maximum junction temperature = 150 °C, Ta: Peripheral temperature [°C], θja: Thermal resistance of package-ambience [°C / W], Pd : Package Power dissipation [W], Pc: Power dissipation [W], V_{CC}: Input Voltage, V_{OUT:} Output Voltage, Io: Load, I_{CC2}: Bias Current2

Package Power dissipation	: Pd (W) = (Тјтах - Та) / θја
Power dissipation	$: Pc (W) = (V_{CC} - V_{OUT}) \times Io + V_{CC} \times I_{CC2}$

7. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

10. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes – continued

11. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be

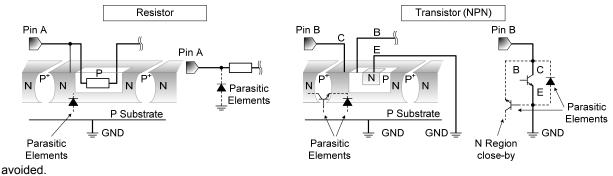


Figure 19. Example of monolithic IC structure

12. Thermal Shutdown Circuit(TSD)

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

13. Over Current Protection Circuit (OCP)

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

14. Applications or inspection processes where the potential of the VCC pin or other pins may be reversed from their normal state may cause damage to the IC's internal circuitry or elements. Use an output pin capacitance of 1000µF or lower in case VCC is shorted with the GND pin while the external capacitor is charged. Insert a diode in series with VCC to prevent reverse current flow, or insert bypass diodes between VCC and each pin.

15. Positive voltage surges on VCC pin

A power zener diode should be inserted between VCC and GND for protection against voltage surges of more than 50 V on the VCC pin.

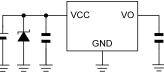


Figure 20. Application Examples 1

16. Negative voltage surges on VCC pin

A schottky barrier diode should be inserted between VCC and GND for protection against voltages lower than GND on the VCC pin.

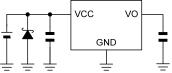


Figure 21. Application Examples 2

Operational Notes – continued

17. Output protection diode

Loads with large inductance components may cause reverse current flow during startup or shutdown. In such cases, a protection diode should be inserted on the output to protect the IC.

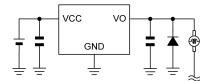
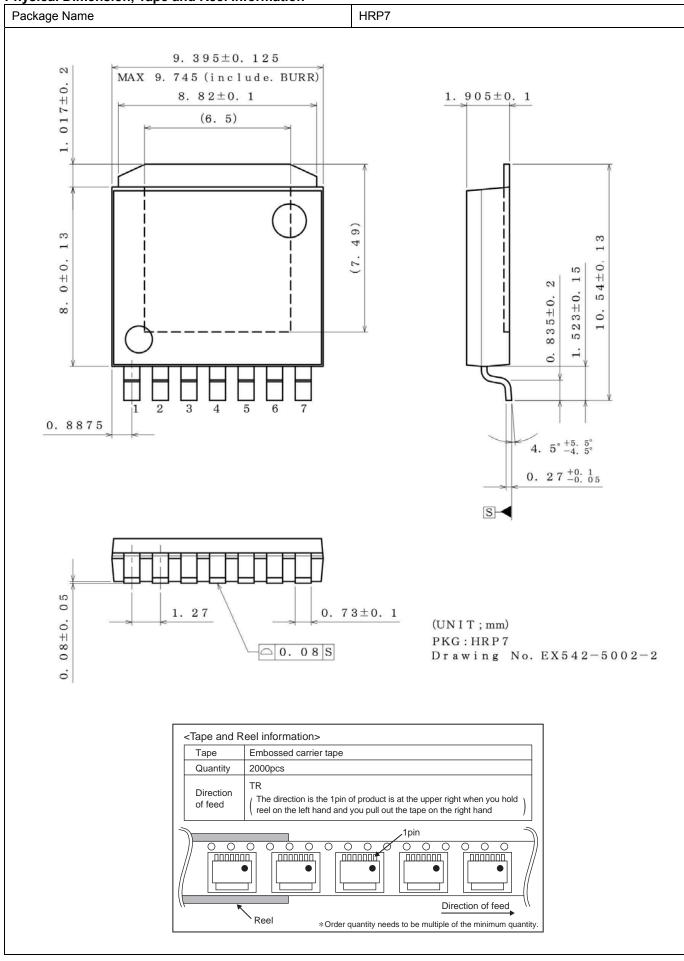
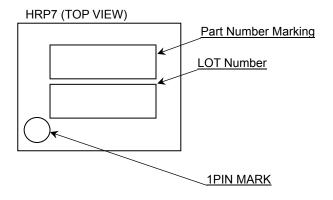


Figure 22. Application Examples 3

Physical Dimension, Tape and Reel Information



Marking Diagram



Product Name	Part Number Marking	
BD3020HFP	BD3020	
BD3021HFP	BD3021	

Revision History

Date	Revision	Changes
10.Nov.2015	001	New Release

Notice

Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA	
CLASSII	CLASSⅢ	CLASS II b		
CLASSⅣ	CLASSI	CLASSⅢ	CLASSⅢ	

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[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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